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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/790,864	03/03/2004	Toshiyuki Takizawa	2004_0347A	3118
513 7590 WENDEROTH, LIND & PONACK, L.L.P. 2033 K STREET N. W. SUITE 800 WASHINGTON, DC 20006-1021			EXAMINER	
			QUINTO, KEVIN V	
			ART UNIT	PAPER NUMBER
			MAIL DATE	DELIVERY MODE
			04/16/2008	PAPER

Please find below and/or attached an Office communication concerning this application or proceeding.

The time period for reply, if any, is set in the attached communication.

Application No. Applicant(s) 10/790 864 TAKIZAWA, TOSHIYUKI Office Action Summary Examiner Art Unit Kevin Quinto 2826 -- The MAILING DATE of this communication appears on the cover sheet with the correspondence address --Period for Reply A SHORTENED STATUTORY PERIOD FOR REPLY IS SET TO EXPIRE 3 MONTH(S) OR THIRTY (30) DAYS. WHICHEVER IS LONGER, FROM THE MAILING DATE OF THIS COMMUNICATION. Extensions of time may be available under the provisions of 37 CFR 1.136(a). In no event, however, may a reply be timely filed after SIX (6) MONTHS from the mailing date of this communication. If NO period for reply is specified above, the maximum statutory period will apply and will expire SIX (6) MONTHS from the mailing date of this communication - Failure to reply within the set or extended period for reply will, by statute, cause the application to become ABANDONED (35 U.S.C. § 133). Any reply received by the Office later than three months after the mailing date of this communication, even if timely filed, may reduce any earned patent term adjustment. See 37 CFR 1.704(b). Status 1) Responsive to communication(s) filed on 17 January 2008. 2a) This action is FINAL. 2b) This action is non-final. 3) Since this application is in condition for allowance except for formal matters, prosecution as to the merits is closed in accordance with the practice under Ex parte Quayle, 1935 C.D. 11, 453 O.G. 213. Disposition of Claims 4) Claim(s) 1-76 is/are pending in the application. 4a) Of the above claim(s) 19-21 and 38-76 is/are withdrawn from consideration. 5) Claim(s) _____ is/are allowed. 6) Claim(s) 1-8.18.23-27.29-31 and 37 is/are rejected. 7) Claim(s) 9-17,22,28 and 32-36 is/are objected to. 8) Claim(s) are subject to restriction and/or election requirement. Application Papers 9) The specification is objected to by the Examiner. 10) The drawing(s) filed on is/are; a) accepted or b) objected to by the Examiner. Applicant may not request that any objection to the drawing(s) be held in abevance. See 37 CFR 1.85(a). Replacement drawing sheet(s) including the correction is required if the drawing(s) is objected to. See 37 CFR 1.121(d). 11) The oath or declaration is objected to by the Examiner. Note the attached Office Action or form PTO-152. Priority under 35 U.S.C. § 119 12) Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f). a) All b) Some * c) None of: Certified copies of the priority documents have been received. 2. Certified copies of the priority documents have been received in Application No. Copies of the certified copies of the priority documents have been received in this National Stage application from the International Bureau (PCT Rule 17.2(a)). * See the attached detailed Office action for a list of the certified copies not received. Attachment(s) 1) Notice of References Cited (PTO-892) 4) Interview Summary (PTO-413) Paper No(s)/Mail Date. Notice of Draftsperson's Patent Drawing Review (PTO-948)

Information Disclosure Statement(s) (PTO/SB/08)
 Paper No(s)/Mail Date ______.

5) Notice of Informal Patent Application

6) Other:

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DETAILED ACTION

Response to Arguments

1. Applicant's arguments filed January 17, 2008 have been fully considered but they are not persuasive. The applicant fails to discuss why claims 1-8, 18, 23-27, 29, 30, 31, and 37 are patentable over the Shakuda reference (USPN 5,825,052) and only reiterates the language of claim 1 without pointing out the difference between the claimed invention and the Shakuda reference. Therefore the rejection of claims 1-8, 18, 23-27, 29, 30, 31, and 37 using Shakuda (USPN 5,825,052) under 35 USC § 102 and 35 USC § 103 stand.

Claim Rejections - 35 USC § 102

The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

- (b) the invention was patented or described in a printed publication in this or a foreign country or in public use or on sale in this country, more than one year prior to the date of application for patent in the United States
- Claims 1-5, 7, 8, 18, 23, 24, 26, 27, 29, 30, 31, and 37 are rejected under 35
 U.S.C. 102(b) as being anticipated by Shakuda (USPN 5,825,052).
- 4. In reference to claim 1, Shakuda (USPN 5,825,052) discloses a material which meets the claim. Figure 1 of Shakuda discloses a p-type semiconductor comprising a plurality of elements. One of the elements is a localized band formation element (phosphorus, arsenic) which is isovalent with at least one of elements which compose

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the p-type semiconductor (nitrogen) and has a smaller electronegativity than the electronegativity of the element (column 4, lines 1-45, column 8, lines 66-67, column 9, lines 1-65).

- 5. With regard to claim 2, Shakuda discloses that the p-type semiconductor (column 4, lines 26-29, column 9, lines 66-67, column 10, lines 1-2) has another element which is an acceptor element (beryllium, magnesium, zinc, cadmium, calcium) that has fewer valence electrons than valence electrons of at least one of the elements (nitrogen) which compose the semiconductor.
- In reference to claim 3, an amount of the localized band formation element is larger than an amount of the acceptor element in the p-type semiconductor.
- With regard to claim 4, the acceptor element has a lower energy level than a top of an energy band for that of the localized band formation element.
- In reference to claim 5, the acceptor element and the localized band formation element are distributed uniformly.
- In reference to claim 7, the p-type semiconductor is a compound semiconductor (gallium nitride).
- With regard to claim 8, the p-type semiconductor is a nitride semiconductor (gallium nitride).
- 11. In reference to claim 18, the energy gap between an energy level which the acceptor element has and a top of an energy band which the localized band formation element has is higher than the thermal energy at the temperature when the semiconductor is used.

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12. With regard to claim 23, another of the elements is an acceptor element (beryllium, magnesium, zinc, cadmium, calcium) which has fewer valence electrons than valence electrons of at least one of the elements (nitrogen) which compose the p-type semiconductor. The acceptor element has a lower energy level than a top of an energy band for that of the localized band formation element.

- 13. In reference to claim 24, another of the elements is an acceptor element (beryllium, magnesium, zinc, cadmium, calcium) which has fewer valence electrons than valence electrons of at least one of the elements (nitrogen) which compose the ptype semiconductor. The acceptor element and the localized band formation element are distributed uniformly.
- In reference to claim 26, the p-type semiconductor is a compound semiconductor (gallium nitride).
- With regard to claim 27, the p-type semiconductor is a nitride semiconductor (gallium nitride).
- 16. With regard to claim 29, Shakuda discloses that the p-type semiconductor is a nitride semiconductor (gallium nitride) and has an acceptor (column 4, lines 26-29, column 9, lines 66-67, column 10, lines 1-2) element (beryllium, magnesium, zinc, cadmium, calcium) which has fewer valence electrons than valence electrons of at least one of the elements (nitrogen) which compose the p-type semiconductor.
- 17. In reference to claim 30, Shakuda discloses that the p-type semiconductor is a nitride semiconductor (gallium nitride) and the localized band formation element is

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phosphorus or arsenic (column 4, lines 1-45, column 8, lines 66-67, column 9, lines 1-65).

- 18. In reference to claim 31, the p-type semiconductor is a nitride semiconductor which has at least one Group III element including boron (column 10, lines 10-14) and at least one Group V element including nitrogen.
- 19. In reference to claim 37, there is an acceptor element (beryllium, magnesium, zinc, cadmium, calcium) which has fewer valence electrons than valence electrons of at least one of the elements (nitrogen) which compose the p-type semiconductor. The energy gap between an energy level which the acceptor element has and a top of an energy band which the localized band formation element has is higher than the thermal energy at the temperature when the p-type semiconductor is used.

Claim Rejections - 35 USC § 103

20. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

- Claims 6 and 25 are rejected under 35 U.S.C. 103(a) as being unpatentable over Shakuda (USPN 5,825,052).
- 22. In reference to claim 6, Shakuda does not teach the exact atom% for the localized band formation element as that claimed by the applicant. However::

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"[W]here the general conditions of a claim are disclosed in the prior art, it is not inventive to discover the optimum or workable ranges by routine experimentation." In re Aller, 220 F.2d 454, 456, 105 USPQ 233, 235 (CCPA 1955).

Therefore claim 6 is not patentably distinguishable over the Shakuda reference.

23. In reference to claim 25, Shakuda does not teach the exact atom% for the localized band formation element as that claimed by the applicant. However::

"[W]here the general conditions of a claim are disclosed in the prior art, it is not inventive to discover the optimum or workable ranges by routine experimentation." In re Aller, 220 F.2d 454, 456, 105 USPQ 233, 235 (CCPA 1955).

Therefore claim 25 is not patentably distinguishable over the Shakuda reference.

Allowable Subject Matter

- 24. Claims 9-17, 22, 28, and 32-36 are objected to as being dependent upon a rejected base claim, but would be allowable if rewritten in independent form including all of the limitations of the base claim and any intervening claims.
- 25. The following is a statement of reasons for the indication of allowable subject matter: the examiner is unaware of any prior art which suggests a p-type nitride semiconductor containing a localized band formation element which has a smaller electronegativity as one of the elements of the semiconductor as suggested in claims 9, 22, and 28. The examiner is also unaware of any prior art having a p-type oxide semiconductor containing a localized band formation element which has a smaller electronegativity as one of the elements of the semiconductor as suggested in claims 13 and 32-36.

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Conclusion

 THIS ACTION IS MADE FINAL. Applicant is reminded of the extension of time policy as set forth in 37 CFR 1.136(a).

A shortened statutory period for reply to this final action is set to expire THREE MONTHS from the mailing date of this action. In the event a first reply is filed within TWO MONTHS of the mailing date of this final action and the advisory action is not mailed until after the end of the THREE-MONTH shortened statutory period, then the shortened statutory period will expire on the date the advisory action is mailed, and any extension fee pursuant to 37 CFR 1.136(a) will be calculated from the mailing date of the advisory action. In no event, however, will the statutory period for reply expire later than SIX MONTHS from the mailing date of this final action.

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Kevin Quinto whose telephone number is (571)272-1920. The examiner can normally be reached on M-F 8AM-5PM.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Sue Purvis can be reached on (571) 272-1236. The fax phone number for the organization where this application or proceeding is assigned is 571-273-8300.

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Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free). If you would like assistance from a USPTO Customer Service Representative or access to the automated information system, call 800-786-9199 (IN USA OR CANADA) or 571-272-1000.

/Kevin Quinto/ Examiner, Art Unit 2826

/A. Sefer/ Primary Examiner Art Unit 2826